

50V N-Channel Enhancement Mode MOSFET – ESD Protected

Voltage 50 V Current 500mA

Features

- RDS(ON), VGS@10V, ID@500mA<1.45Ω
- RDS(ON), VGS@4.5V, ID@200mA<1.95Ω
- RDS(ON), VGS@2.5V, ID@100mA<4.0Ω
- RDS(ON), VGS@1.8V, ID@10mA<6.0Ω
- Advanced Trench Process Technology
- ESD Protected 2KV HBM
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

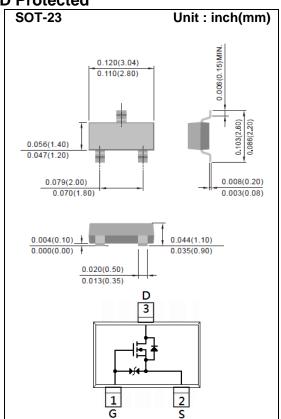
Mechanical Data

Case: SOT-23 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A38



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	50	V
Gate-Source Voltage		V _G s	<u>+</u> 20	V
Continuous Drain Current		ID	500	mA
Pulsed Drain Current		I _{DM}	1200	mA
Power Dissipation	T _A =25°C	Б	500	mW
	Derate above 25°C	P _D	4	mW/°C
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		ReJA	250	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V,I _D =250uA		50	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.5	0.86	1.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =500mA	-	1.2	1.45	- Ω	
		V _{GS} =4.5V,I _D =200mA	-	1.3	1.95		
		V _{GS} =2.5V,I _D =100mA	-	1.7	4.0		
		V _{GS} =1.8V,I _D =10mA	-	4.0	6.0		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =50V,V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 10	uA	
Dynamic (Note 4)							
Total Gate Charge	Q_g)/ 05\/ L 500 A	-	0.95	-	nC	
Gate-Source Charge	Q_gs	$V_{DS}=25V, I_{D}=500mA, V_{GS}=4.5V$	-	0.34	-		
Gate-Drain Charge	Q_gd	VGS=4.5V	-	0.32	-		
Input Capacitance	Ciss), OF),), O),	-	36	-	pF	
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V,	-	11	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	6.6	-		
Turn-On Delay Time	td _(on)	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	2.3	-		
Turn-On Rise Time	tr	V _{DD} =25V, I _D =500mA,	-	20	-	ns	
Turn-Off Delay Time	td _(off)	V _{GS} =10V, R _G =6Ω (Note 1,2)	-	7	-		
Turn-Off Fall Time	tf	RG=012 (Note 1,2)	-	20	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	500	mA	
Diode Forward Voltage	V _{SD}	I _S =500mA, V _{GS} =0V	-	0.9	1.5	٧	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing



TYPICAL CHARACTERISTIC CURVES

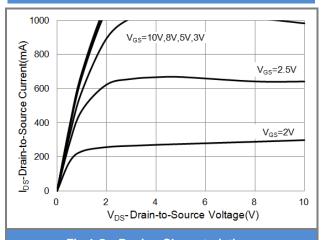


Fig.1 On-Region Characteristics

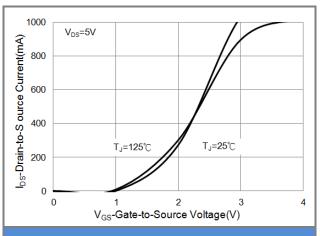


Fig.2 Transfer Characteristics

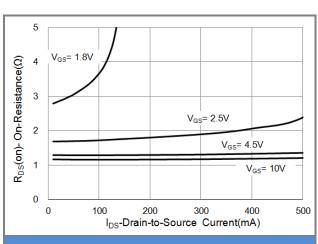


Fig.3 On-Resistance vs. Drain Current

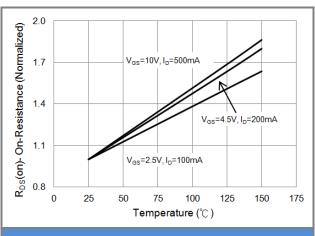
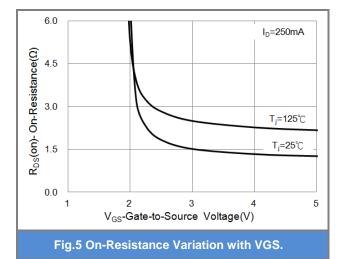


Fig.4 On-Resistance vs. Junction temperature



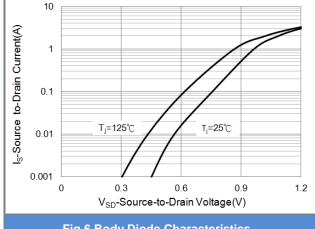


Fig.6 Body Diode Characteristics



TYPICAL CHARACTERISTIC CURVES

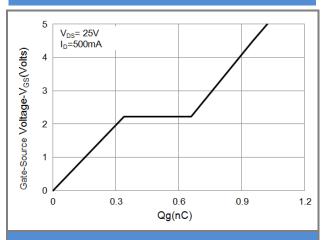


Fig.7 Gate-Charge Characteristics

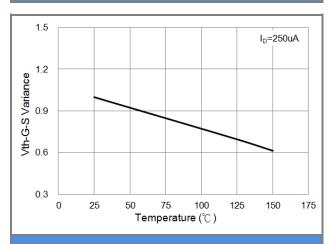


Fig.9 Threshold Voltage Variation with Temperature.

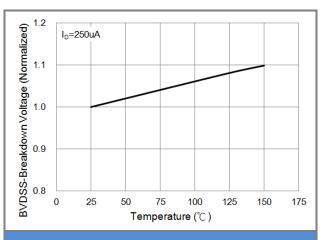


Fig.8 Breakdown Voltage Variation vs. Temperature

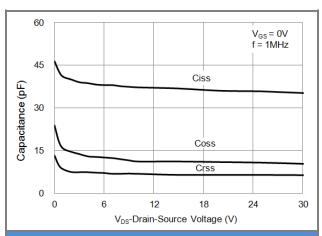


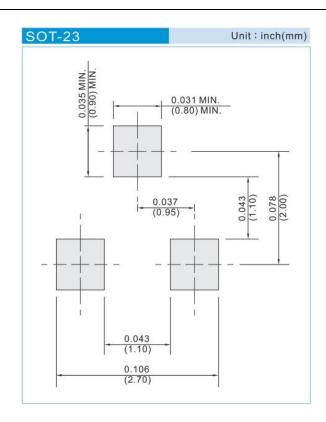
Fig.10 Capacitance vs. Drain-Source Voltage.



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3438	SOT-23	3K pcs / 7" reel	A38	
PJA3438	SOT-23	12K pcs / 13" reel	A38	

MOUNTING PAD LAYOUT





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